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Double-Mesoscopic HTM-Free Perovskite Solar Cells: Overcoming Charge Transport Limitation by sputtered 40 nm Al_2O_3 isolating layer

G. Mathiazhagan^a, L. Wagner^a, S. Bogati^a, Kubra Yasaroglu Ünal^{a,c}, Thomas Kroyer^a, S. Mastroianni^{a,b}, and A. Hinsch^a
gayathri.mathiazhagan@ise.fraunhofer.de

^a Fraunhofer Institute for Solar Energy Systems ISE, Heidenhofstr. 2, D-79110 Freiburg, Germany

^b Freiburg Materials Research Center FMF, Albert-Ludwigs- University Freiburg, Stefan-Meier-Straße 25, D-79140 Freiburg, Germany

^c IPCMS, Université de Strasbourg, CNRS UMR 7504, 23 rue du Loess, B. P. 43, 67034 Strasbourg Cedex 2, France

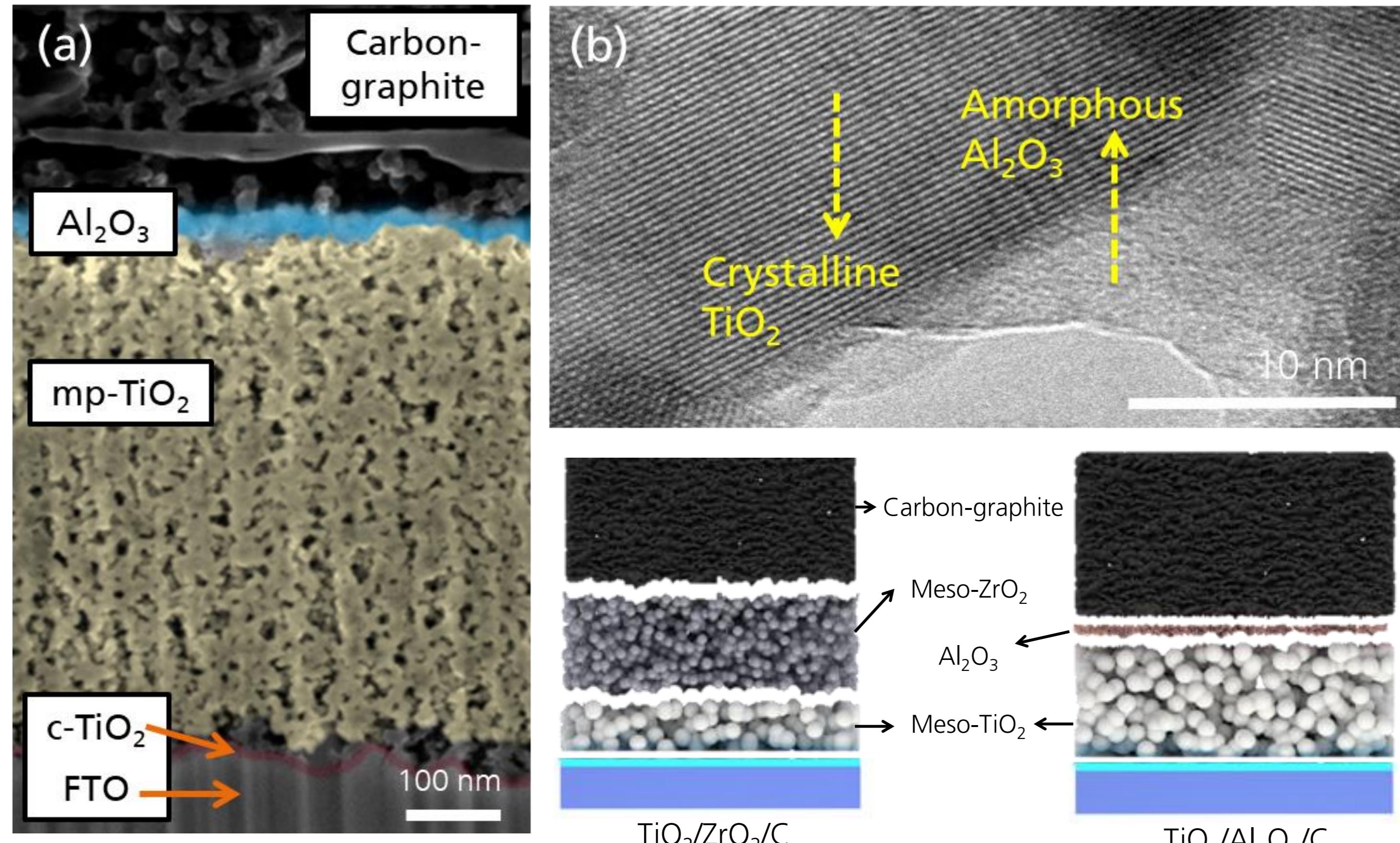
INTRODUCTION

CARBON-GRAFITE BASED PEROVSKITE SOLAR CELLS (C-PSCs) ¹:

- In C-PSCs the space layer is fundamental in order to:
 - Prevent direct shunts between the mesoporous TiO_2 (mp- TiO_2) electron transport layer and the carbon-graphite interface
 - Prevent electron recombination at the TiO_2 /carbon-graphite interface

IN THIS WORK:

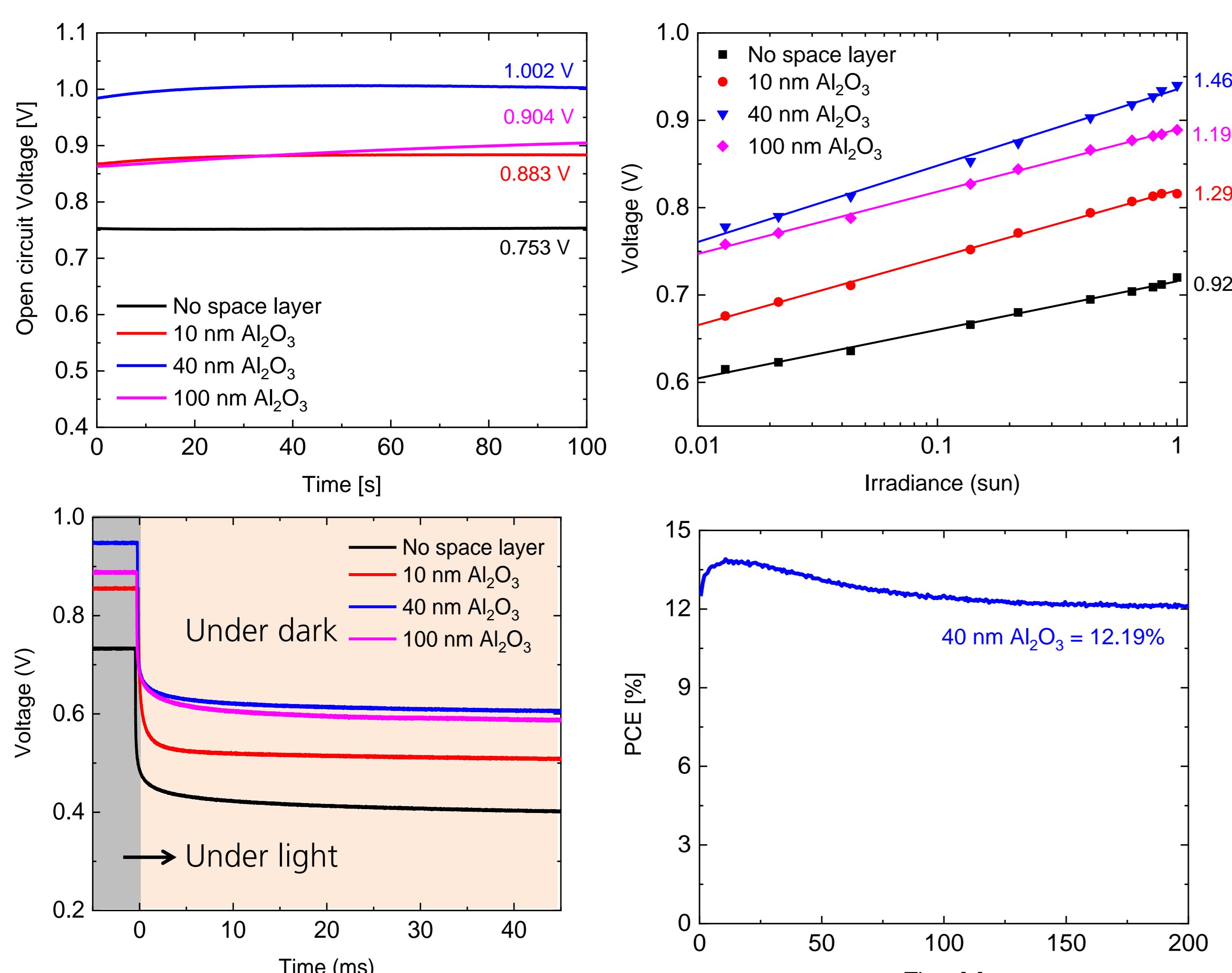
- Crystalline TiO_2 conformally covered by amorphous sputtered Al_2O_3 creating pseudo-porosity



FIB-SEM and TEM images of double mesoscopic carbon-graphite based perovskite solar cells (C-PSCs)

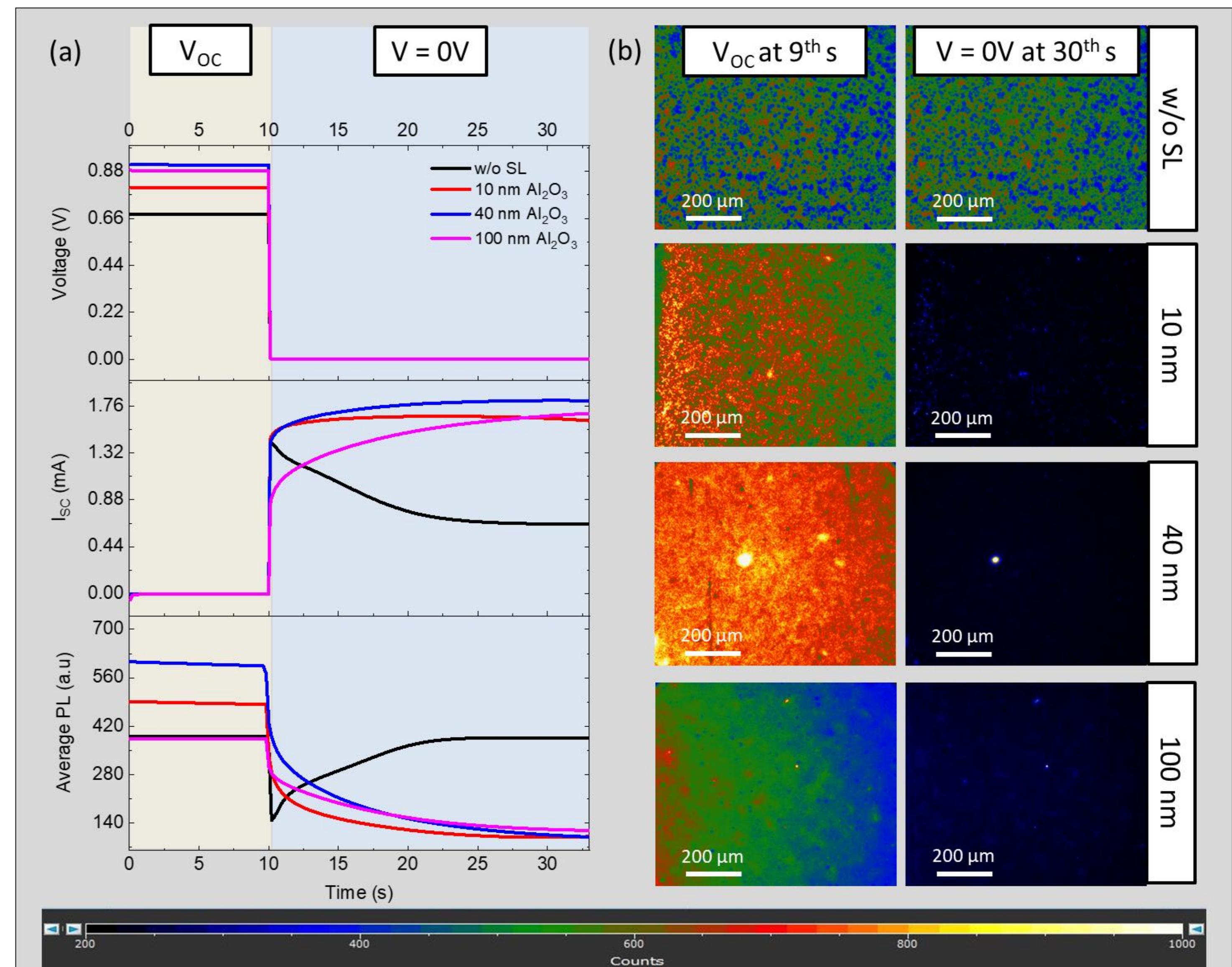
STABLE VOLTAGE, V_{OC} DECAY & LOW SUN INTENSITY MEASUREMENT

- Recombination of trapped e^- in mp- TiO_2 with carbon is efficiently blocked by the 40 nm thin $\text{Al}_2\text{O}_3 \rightarrow$ long living secondary charges at higher voltage
- Voltage > 0.75 V at low sun intensity \rightarrow shunt-free, pinhole-free
- High n factor \rightarrow mono- & bi-molecular recombination



SPACE-RESOLVED PHOTOLUMINESCENCE (PL)

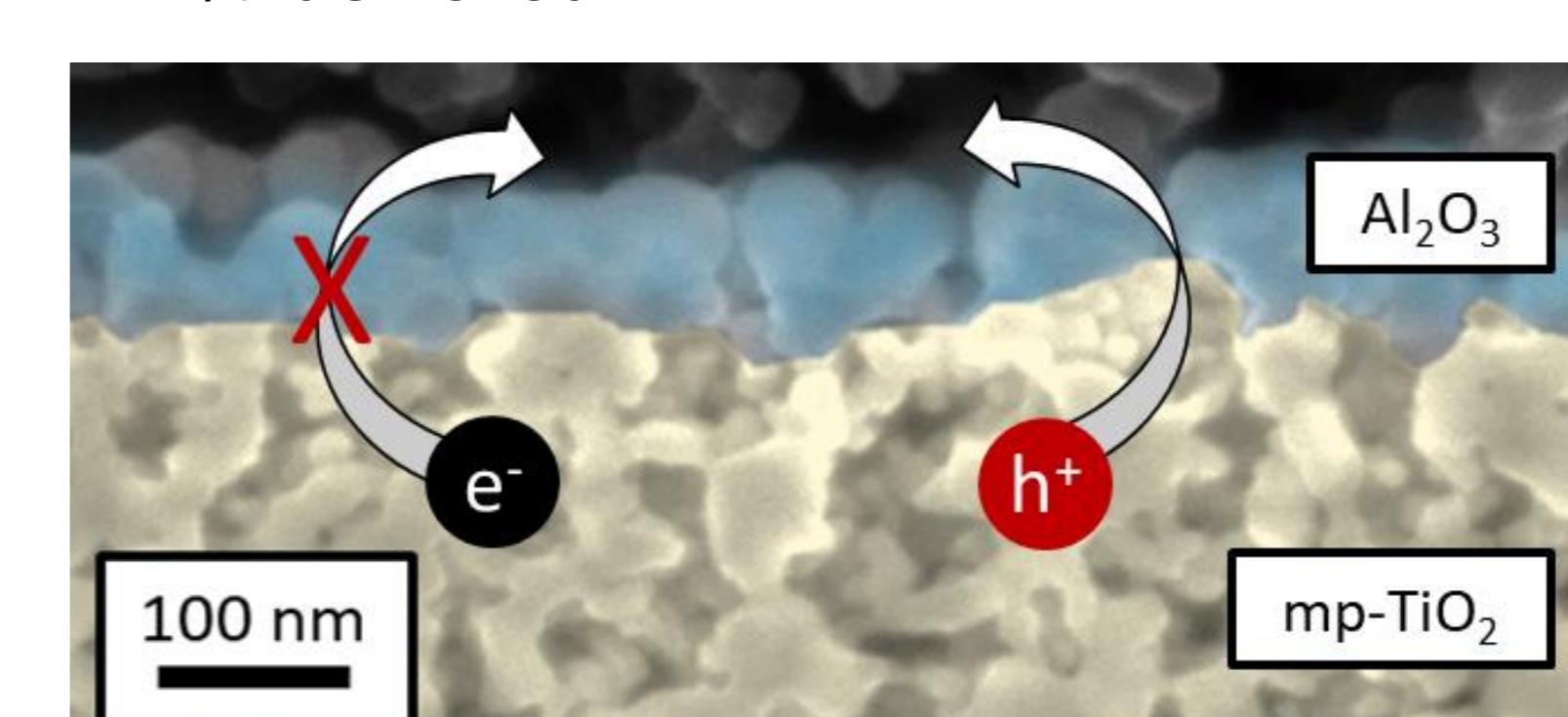
- At open circuit \rightarrow PL contributed by primary charge carrier recombination
- At short circuit \rightarrow complete extraction of charges leads to zero PL (ideal case)
- PL quenching \rightarrow to measure charge transport efficiency
- The addition of Al_2O_3 space layer:
 - Stable quenched PL and charge extraction
 - 40 nm Al_2O_3 thickness shows efficient charge extraction



(a) Voltage, current and PL measured simultaneously while switching between open circuit (OC) and short circuit (SC) conditions (b) PL images at 9th and 30th s of measurement (9th s in OC; 30th s in SC)

CONCLUSION

- Shunt-free pinhole-free 40 nm Al_2O_3
- e^- in mp- TiO_2 are blocked from reaching the carbon-graphite interface: Stable voltage of 1 V reached
- Stable quenched PL \rightarrow Efficient charge extraction
- Pseudo-porous $\text{Al}_2\text{O}_3 \rightarrow$ Allows good pore filling
- Stable PCE of 12.1% achieved ²



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¹ L.Wagner et al. ACS Energy Lett. 2018,3, 1122-1127

² G.Mathiazhagan et al. – ACS Applied nano materials. Manuscript under revision

